

**QUADRUPLE 3-STATE BUFFERS OE LOW**

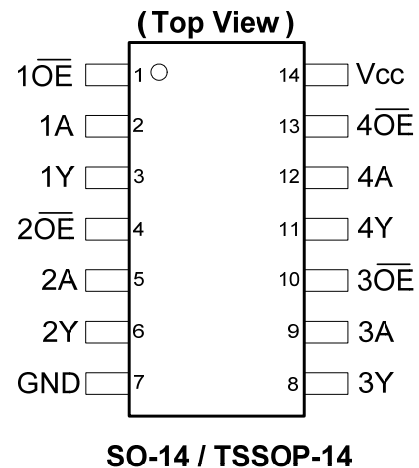
**Description**

The 74HC125 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a high logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 2.0V to 6.0V.

**Features**

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or sources 4mA at  $V_{CC} = 4.5V$
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

**Pin Assignments**



**Applications**

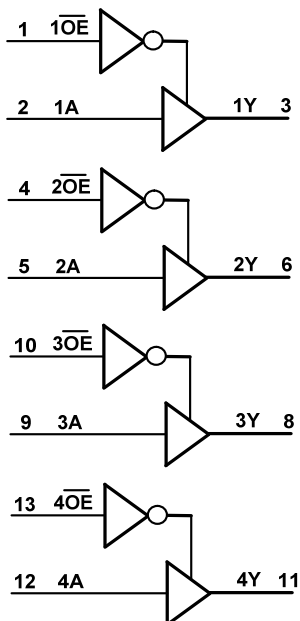
- General Purpose Logic
- Wide array of products such as:
  - PCs, Networking, Notebooks, Netbooks
  - Computer Peripherals, Hard Drives, CD/DVD ROM
  - TV, DVD, DVR, Set Top Box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.  
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.  
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Pin Descriptions

Pin Number	Pin Name	Function
1	$1\overline{OE}$	Data Enable Input (active low)
2	1A	Data Input
3	1Y	Data Output
4	$2\overline{OE}$	Data Enable Input (active low)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	$3\overline{OE}$	Data Enable Input (active low)
11	4Y	Data Output
12	4A	Data Input
13	$4\overline{OE}$	Data Enable Input (active low)
14	V <sub>CC</sub>	Supply Voltage

## Logic Diagram



## Function Table

Inputs		Output
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

### Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
V <sub>I</sub>	Input Voltage Range note 3)	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V or V <sub>I</sub> > V <sub>CC</sub> +0.5V	±20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < -0.5V or V <sub>O</sub> > V <sub>CC</sub> +0.5V	±20	mA
I <sub>O</sub>	Continuous Output Current -0.5V < V <sub>O</sub> < V <sub>CC</sub> +0.5V	+/- 25	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

- Notes:
- Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
  - Input Voltage cannot exceed V<sub>CC</sub> to the extent the Maximum clamp current is exceeded.

### Recommended Operating Conditions (Note 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		2.0	6.0	V
V <sub>I</sub>	Input Voltage		0	V <sub>CC</sub>	V
V <sub>O</sub>	Output Voltage		0	V <sub>CC</sub>	V
Δt/ΔV	Input Transition Rise or Fall Rate	V <sub>CC</sub> = 2.0V		625	ns/V
		V <sub>CC</sub> = 4.5V		140	
		V <sub>CC</sub> = 6.0V		85	
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C

- Note: 6. Unused inputs should be held at V<sub>CC</sub> or Ground.

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
				Min	Max	Min	Max	
V <sub>IH</sub>	High-level Input Voltage		2.0V	1.5		1.5		V
			4.5V	3.15		3.15		
			6.0V	4.2		4.2		
V <sub>IL</sub>	Low-level Input voltage		2.0V		0.5		0.5	V
			4.5V		1.35		1.35	
			6.0V		1.8		1.8	
V <sub>OH</sub>	High-level Output Voltage	I <sub>OH</sub> = -20μA	2.0V	1.9		1.9		V
		I <sub>OH</sub> = -20μA	4.5V	4.4		4.4		
		I <sub>OH</sub> = -20μA	6.0V	5.9		5.9		
		I <sub>OH</sub> = -4.0mA	4.5V	3.84		3.7		
		I <sub>OH</sub> = -5.2mA	6.0V	5.34		5.2		
V <sub>OL</sub>	Low-level Output Voltage	I <sub>OL</sub> = 20μA	2.0V		0.1		0.1	V
		I <sub>OL</sub> = 20μA	4.5V		0.1		0.1	
		I <sub>OL</sub> = 20μA	6.0V		0.1		0.1	
		I <sub>OL</sub> = 4mA	4.5V		0.33		0.44	
		I <sub>OL</sub> = 5.2mA	6.0V		0.33		0.44	
I <sub>OZ</sub>	Z State Leakage Current	V <sub>O</sub> = 0 to 6.0V V <sub>I</sub> = GND or 6.0V	6.0V		± 5.0		± 10	μA
I <sub>I</sub>	Input Current	V <sub>I</sub> = GND to 5.5V	6.0V		± 1		± 1	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> , I <sub>O</sub> = 0	6.0V		20		40	μA

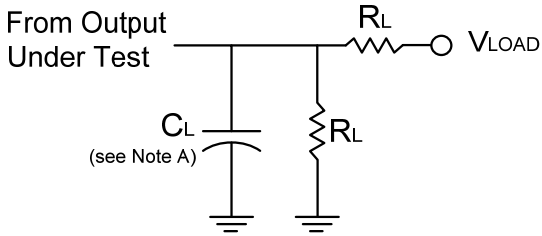
**Switching Characteristics**

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C	-40°C to +125°C	Unit
				Min	Typ.	Max	Max	Max	
t <sub>PD</sub>	Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 50 pF	2.0V	—	30	100	125	150	ns
			4.5V	—	11	20	25	30	
			6.0V	—	9	17	21	26	
t <sub>EN</sub>	Enable Time OE <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 50 pF	2.0V	—	41	125	155	190	ns
			4.5V	—	15	25	31	38	
			6.0V	—	12	21	26	32	
t <sub>DIS</sub>	Disable Time OE to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 50 pF	2.0V	—	41	125	155	190	ns
			4.5V	—	15	25	31	38	
			6.0V	—	12	21	26	32	
t <sub>t</sub>	Transition time	Figure 1 C <sub>L</sub> = 50 pF	2.0V	—	14	60	75	90	ns
			4.5V	—	5	12	15	18	
			6.0V	—	4	10	13	15	

**Operating Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

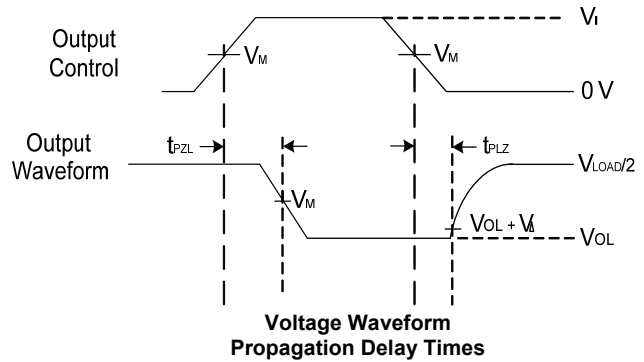
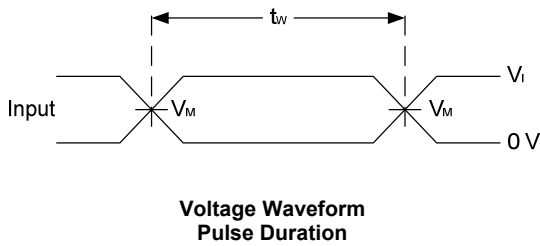
Parameter		Test Conditions	V <sub>CC</sub> = 6V	Unit
			Typ	
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	f = 1MHz	22	pF
C <sub>I</sub>	Input Capacitance	V <sub>I</sub> = V <sub>CC</sub> – or GND	4	pF

**Parameter Measurement Information**



TEST	Condition
$t_{PLZ}$ (see Notes D and E)	Vload
$t_{PZL}$ (see Notes D and F)	Vload

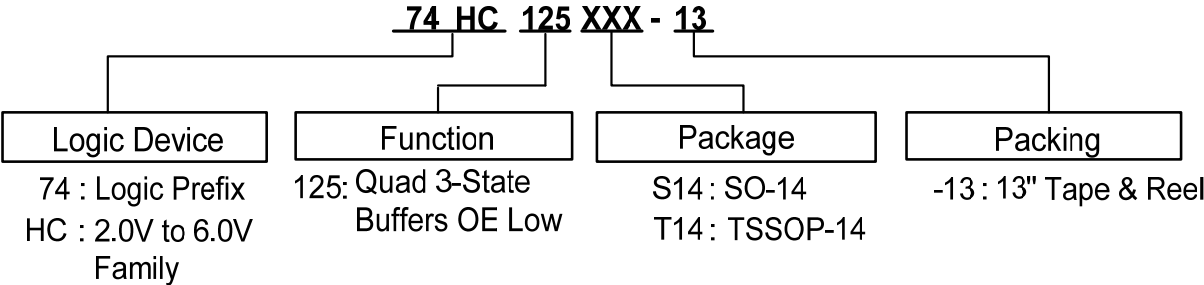
$V_{CC}$	Inputs		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
2.0V to 6.0V	$V_{CC}$	$\leq 3ns$	$V_{CC}/2$	$2 \times V_{CC}$	15,50 pF	2 K $\Omega$	10% of $V_{CC}$



**Figure 1 Load Circuit and Voltage Waveforms**

- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq 1$  MHz.
  - C. The inputs are measured one at a time with one transition per measurement.
  - D. For the 3 state device  $t_{PLZ}$  and  $t_{PZL}$  are the same as  $t_{PD}$ .
  - E.  $t_{PZL}$  is measured at  $V_M$ .
  - D.  $t_{PLZ}$  is measured at  $V_{OL} + V_{\Delta}$ .

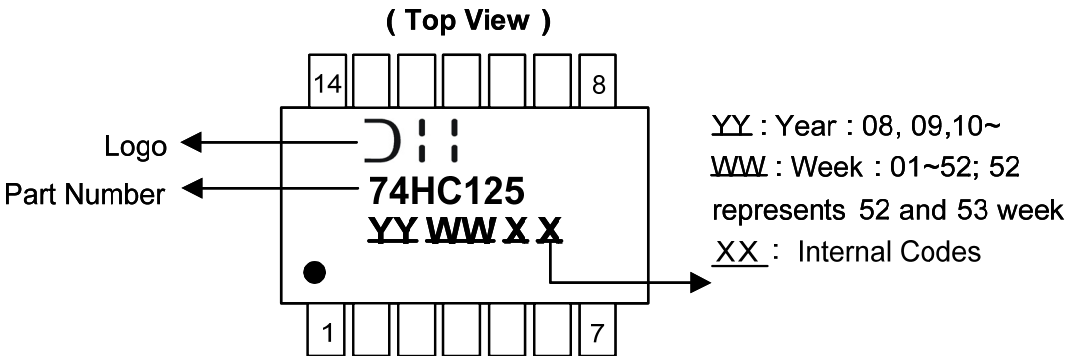
**Ordering Information**



Device	Package Code	Packaging	7" Tape and Reel	
			Quantity	Part Number Suffix
74HC125S14-13	S14	SO-14	2500/Tape & Reel	-13
74HC125T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

**Marking Information**

(1) SO-14, TSSOP-14

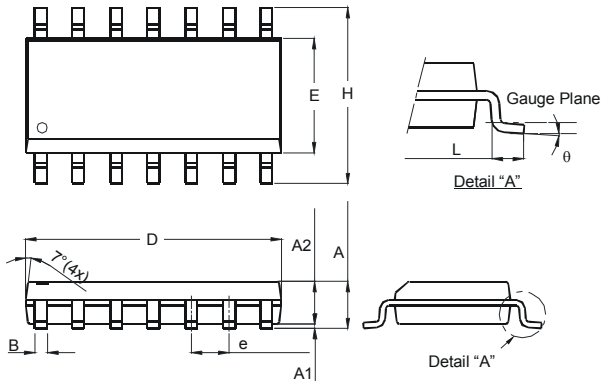


Part Number	Package
74HC125S14	SO-14
74HC125T14	TSSOP-14

**Package Outline Dimensions** (All dimensions in mm.)

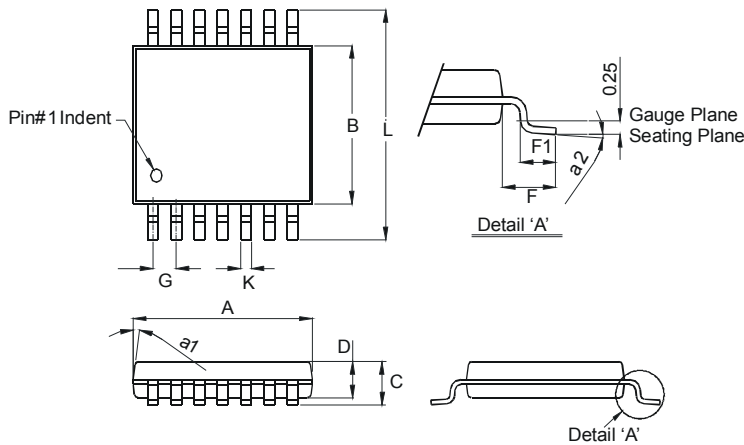
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

**Package Type: SO-14**



SO-14		
Dim	Min	Max
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
$\theta$	0°	8°
All Dimensions in mm		

**Package Type: TSSOP-14**

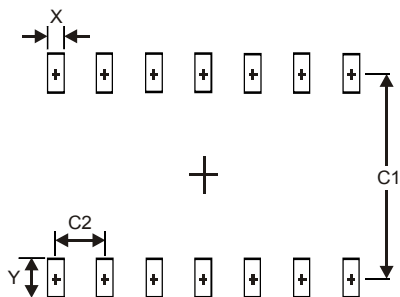


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

## Suggested Pad Layout

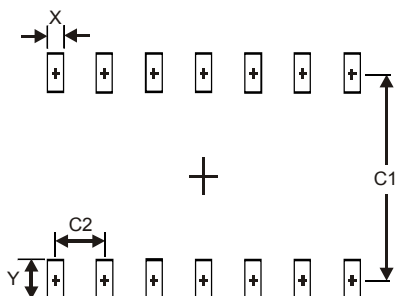
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65



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